

SOT-23 Formed SMD Package

BSR18A

SILICON LOW-POWER SWITCHING TRANSISTORS

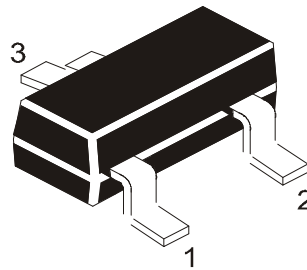
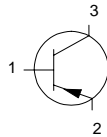
P-N-P silicon transistor

Marking

BSR18A = T92

Pin configuration

- 1 = BASE
- 2 = EMITTER
- 3 = COLLECTOR



ABSOLUTE MAXIMUM RATINGS

Collector-base voltage (open emitter)	$-V_{CBO}$ max.	40 V
Collector-emitter voltage (open base)	$-V_{CEO}$ max.	40 V
Collector current (DC)	$-I_C$ max.	200 mA
Total power dissipation up to $T_{amb} = 25\text{ }^\circ\text{C}$	P_{tot} max.	250 mW
Junction temperature	T_j max.	150 $^\circ\text{C}$
DC current gain		
$-I_C = 10\text{ mA}; -V_{CE} = 1\text{ V}$	BSR18A h_{FE}	100 to 300
Transition frequency at $f = 500\text{ MHz}$		
$-I_C = 10\text{ mA}; -V_{CE} = 20\text{ V}$	f_T	> 250 MHz

BSR18A

RATINGS (at $T_A = 25^\circ\text{C}$ unless otherwise specified)

Limiting values

Collector-base voltage (open emitter)	$-V_{CB0}$	max.	40 V
Collector-emitter voltage (open base)	$-V_{CE0}$	max.	40 V
Emitter-base voltage (open collector)	$-V_{EB0}$	max.	5 V
Collector current (d.c.)	$-I_C$	max.	200 mA
Total power dissipation up to $T_{amb} = 25^\circ\text{C}$	P_{tot}	max.	250 mW
Storage temperature	T_{stg}		-55 to +150 °C
Junction temperature	T_j	max.	150 °C

THERMAL RESISTANCE

From junction to ambient	$R_{th\ j-a}$		500 K/W
--------------------------	---------------	--	---------

CHARACTERISTICS

$T_{amb} = 25^\circ\text{C}$ unless otherwise specified

Collector cut-off current

$I_E = 0; -V_{CB} = 30\text{ V}$	$-I_{CB0}$	<	50 nA
----------------------------------	------------	---	-------

Emitter cut-off current

$I_C = 0; -V_{EB} = 3\text{ V}$	$-I_{EB0}$	<	50 nA
---------------------------------	------------	---	-------

Saturation voltages

$-I_C = 10\text{ mA}; -I_B = 1\text{ mA}$	$-V_{CEsat}$	<	250 mV
	$-V_{BEsat}$	650 to 850	mV

$-I_C = 50\text{ mA}; -I_B = 5\text{ mA}$	$-V_{CEsat}$	<	400 mV
	$-V_{BEsat}$	<	950 mV

Collector capacitance at $f = 100\text{ kHz}$

$I_E = I_e = 0; -V_{CB} = 5\text{ V}$	C_c	<	4,5 pF
---------------------------------------	-------	---	--------

Emitter capacitance at $f = 100\text{ kHz}$

$I_C = I_c = 0; -V_{EB} = 0,5\text{ V}$	C_e	<	10 pF
---	-------	---	-------

D.C. current gain*

$-I_C = 0,1\text{ mA}; -V_{CE} = 1\text{ V}$	h_{FE}	>	60
$-I_C = 1,0\text{ mA}; -V_{CE} = 1\text{ V}$	h_{FE}	>	80
$-I_C = 10\text{ mA}; -V_{CE} = 1\text{ V}$	h_{FE}	100 to 300	
$-I_C = 50\text{ mA}; -V_{CE} = 1\text{ V}$	h_{FE}	>	60
$-I_C = 100\text{ mA}; -V_{CE} = 1\text{ V}$	h_{FE}	>	30

Transition frequency at $f = 100\text{ MHz}$

$-I_C = 10\text{ mA}; -V_{CE} = 20\text{ V}$	f_T	>	250 MHz
--	-------	---	---------

Small signal current gain

$I_C = 1\text{ mA}; V_{CE} = 10\text{ V}; f = 1\text{ kHz}$	h_{fe}	>	100
		<	400

Packing Detail

PACKAGE	STANDARD PACK		INNER CARTON BOX		OUTER CARTON BOX		
	Details	Net Weight/Qty	Size	Qty	Size	Qty	Gr Wt
SOT-23 T&R	3K/reel	136 gm/3K pcs	3" x 7.5" x 7.5"	12.0K	17" x 15" x 13.5"	192.0K	12 kgs
			9" x 9" x 9"	51.0K	19" x 19" x 19"	408.0K	28 kgs
	10K/reel	415 gm/10K pcs	13" x 13" x 0.5"	10.0K	17" x 15" x 13.5"	300.0K	16 kgs

Customer Notes

Component Disposal Instructions

1. CDIL Semiconductor Devices are RoHS compliant, customers are requested to please dispose as per prevailing Environmental Legislation of their Country.
2. In Europe, please dispose as per EU Directive 2002/96/EC on Waste Electrical and Electronic Equipment (WEEE).

Disclaimer

The product information and the selection guides facilitate selection of the CDIL's Semiconductor Device(s) best suited for application in your product(s) as per your requirement. It is recommended that you completely review our Data Sheet(s) so as to confirm that the Device(s) meet functionality parameters for your application. The information furnished on the CDIL Web Site/CD are believed to be accurate and reliable. CDIL however, does not assume responsibility for inaccuracies or incomplete information. Furthermore, CDIL does not assume liability whatsoever, arising out of the application or use of any CDIL product; neither does it convey any license under its patent rights nor rights of others. These products are not designed for use in life saving/support appliances or systems. CDIL customers selling these products (either as individual Discrete Semiconductor Devices or incorporated in their end products), in any life saving/support appliances or systems or applications do so at their own risk and CDIL will not be responsible for any damages resulting from such sale(s).

CDIL strives for continuous improvement and reserves the right to change the specifications of its products without prior notice.



CDIL is a registered Trademark of

Continental Device India Limited

C-120 Naraina Industrial Area, New Delhi 110 028, India.

Telephone + 91-11-2579 6150, 4141 1112 Fax + 91-11-2579 5290, 4141 1119

email@cdil.com www.cdilsemi.com